

LDS105P

Secondary V/I amplifier

Product Specification

Revision 1.4

February 12, 2008

General Description

The LDS105P is a low cost secondary control circuit for low power applications needing constant voltage and constant current control. It implements a simple single-loop control by modifying the internal reference level as a function of current above the current limit threshold. The current loop reduces the reference by 40 mV per mV change at the current sense input. The error amp provides high gain and bandwidth under low voltage operation.

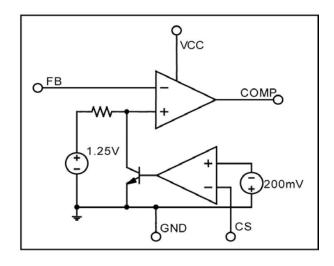
Applications

- Offline Battery Chargers
- Constant V/ Constant I supplies

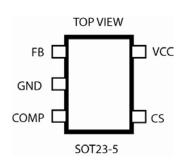
Features

- 1.25V reference
- 200mV current limit threshold
- Error amp output swings near ground for low voltage operation
- High PSRR and line regulation
- Low current consumption
- Open collector output
- Low voltage operation 2.2V
- 10mA current sink
- 50 ppm/°C typical temperature deviation
- RoHS compliant available

Block Diagram

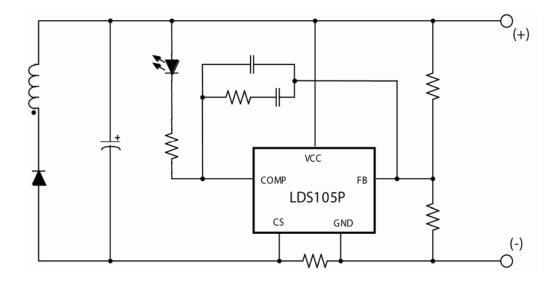


Pin Configuration



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Typical Application



Pin Descriptions

Pin	Pin Name	Function		
1	VCC	Positive supply		
2	GND	Ground		
3	COMP	Output of error amplifier; 10 mA source/sink capability		
4	FB	Inverting input to error amplifier; will have threshold of 1.25V.		
5	CS	Current sense input		

Absolute Maximum Ratings

Parameter	Value	Units
V _{CC} Voltage	20	V
COMP Voltage	20	V
REF Voltage	20	V
CS Voltage (Self limiting diodes)	±1	V
VCC, COMP, REF, CS Current	50	mA
Operating Junction Temperature	150	°C
Lead Temperature (soldering 10 seconds)	260	°C
Storage Temperature Range	-65 to +150	°C
ESD Rating (HBM)	2	KV

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Electrical Specifications

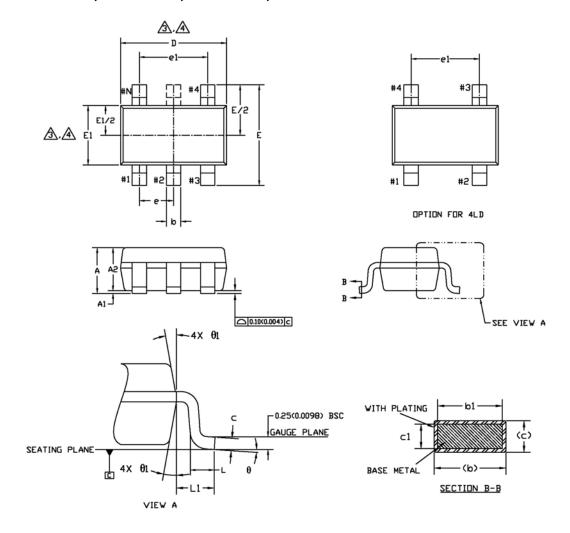
Electrical characteristics are guaranteed over the full temperature range –20°C <Tj<105°C. Ambient temperature must be de-rated based upon power dissipation and package thermal characteristics. Unless otherwise stated, test conditions are VCC = 3V, VCOMP = VFB, ICOMP = 1mA.

Symbol	Parameter	Conditions	Min	Тур	Max	Units	
Vcc	Supply Voltage		2.2		18	V	
Icc	Quiescent Supply Current	VCOMP=1V VCC=15V		0.2	0.5	mA	
Vref	Reference Voltage	Ta=25°C	1.238	1.250	1.263	V	
DVcc	Line regulation	VCC=2.5V to VCC=18V		0.2	1	mV	
DViload	Load Regulation	ICOMP=1mA to 5mA		1	2	mV	
Tcref	Reference Temperature Deviation	-20°C <tj<105°c< td=""><td></td><td>0.5</td><td>1</td><td>%</td></tj<105°c<>		0.5	1	%	
IFB	REF input current		-500		500	nA	
PSRR	Power Supply Rejection	Freq.=300KHz		40		dB	
Av	Error Amplifier Open Loop Gain	ICOMP=2mA, COMP=1V		80		dB	
BW	Unity Gain Frequency	ICOMP=2mA, COMP=1V		2.5		MHz	
VCOMP	Output Saturation Voltage	ICOMP=10mA, VFB=HIGH		200	250	mV	
TRANSC	Output Transconductance	ICOMP=1mA to 20mA		2.5		mA/mV	
lleak	Output Leakage Current	VCOMP=16 VFB=0		200	400	nA	
Vcs	Current copes threshold valtage	Tj=25°C	197		203	mV	
VCS	Current sense threshold voltage	-20 <tj<105°c< td=""><td>195</td><td></td><td>205</td><td></td></tj<105°c<>	195		205		
Gain	Current sense gain to reference	-20 <tj<105°c< td=""><td>36</td><td>40</td><td>44</td><td>mV/mV</td></tj<105°c<>	36	40	44	mV/mV	
loo	Pigg ourrent	Vcs=-200 mV		150			
lcs	Bias current	Vcs=-250 mV		220		μA	

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Package Dimensions

SOT23-3, SOT23-4, SOT23-5, SOT23-6



S	COMMON						
SY M BOL	DIMENSIONS MILLIMETER			DIMENSIONS INCH			
Ľ	MIN.	N□M.	MAX.	MIN.	N□M.	MAX.	
Α	1.20	1.30	1.40	0.047	0.051	0.055	
A1	0.05	-	0.15	0.002	-	0.006	
A2	0.90	1.15	1.30	0.035	0.045	0.051	
b	0.35	-	0.50	0.013	-	0.020	
b1	0.35	0.40	0.45	0.013	0.015	0.017	
С	0.08	-	0.22	0.003	-	0.008	
c1	0.08	0.13	0.20	0.003	0.005	0.007	
ם	2.90 BSC			0.114 BSC			
Ε	2.80 BSC			0.110 BSC			
E1	1.60 BSC		0.062 BSC				
6	0.95 BSC		0.037 BSC				
e1	1.90 BSC		0.074 BSC				
L	0.35	0.45	0.55	0.013	0.017	0.021	
L1	0.60 REF.		0.023 REF.				
θ	0*	4*	8*	0*	4*	8*	
61	10° TYP			10° TYP			

NOTE :

Dimensioning and tolerancing per ASME Y 14.5 M - 1994. Dimensions are in millimeters. Converted inch dimension

Dimensions are in millimeters. Converted inch dimension are not necessarily exact.

Dimension D does not include mold flash, protrusions or gate burrs. Mold flash, protrusion or gate burrs shall not exceed 0.15 mm per side.

Dimension E1 does not include interlead flash or protrusion. Interlead flash or protrusion shall not exceed 0.15 mm per side.

Top package may be smaller than the bottom package Dimension D and E1 are determine at the outermost extremes of the plastic body exclusive of mold flash gate burrs and interlead flash.

Terminal numbers are shown for reference only.

Die is facing up for molding. Die is facing down for trim/form.

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Ordering Information

Device	Operating Tj	%Tol	Pkg Type	Vout	Wrap	Ordering Number
LDS105P	-20C° ≤ 105C°	1.0	SOT-23-5	1.25V	T&R	LDS105DY-M5-12-TL

Note: Lead Free and RoHS compliant.

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